ULTRAFAST RECOVERY

1N5802US 1N5804US 1N5806US

April 20, 2000

TEL:805-498-2111 FAX:805-498-3804 WEB:http://www.semtech.com

SURFACE MOUNT HERMETICALLY SEALED ULTRAFAST RECTIFIER DIODE

Extremely low reverse recovery time

- Hermetically sealed to ensure reliable operation under most sever environmental and electrical stress
- Very low switching losses
- Soft, non-snap off, recovery characteristics
- Very low forward voltage drop

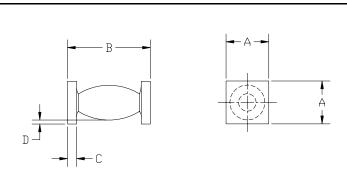
QUICK REFERENCE DATA

- $V_R = 50 150V$
- $I_F = 2.5A$
- trr = 25ns
- $I_R = 1\mu A$

ABSOLUTE MAXIMUM RATINGS (@ 25°C unless otherwise specified)

,					
PARAMETER	SYMBOL	1N5802	1N5804	1N5806	UNITS
Working reverse voltage	V_{RWM}	50	100	150	V
Repetitive reverse voltage	V_{RRM}	50	100	150	٧
Average forward current (@ 75°C, lead length = 0")	I _{F(AV)}		2.5	ı	Α
Repetitive surge current (@ 55°C, in free air, lead length 0")	I _{FRM}	14			А
Non-repetitive surge current ($t_p = 8.3 \text{mS}$, @ $V_R \& T_{jmax}$)	I _{FSM}		35		Α
Operating temperature range	T _{OP}	-65 to +175			°C
Storage temperature range	T _{STG}	-65 to +200			°C

MECHANICAL OUTLINE



DIMENSIONS							
DIM	М	М	INCHES		INCHES NOT		NOTES
	MIN	MAX	MIN	MAX			
Α	2.31	2.62	0.091	0.103			
В	4.27	5.08	0.168	0.200			
С	0.48	0.71	0.019	0.028			
D	0.8	0.91	0.003	0.91	DIM PRE-SOLDER		

These products are qualified to MIL-S-19500/477 and are preferred parts as listed in MIL-STD-701.

They are available as JANTX, and JANTXV versions.





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ELECTRICAL CHARACTERISTICS (@ 25°C unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS	1N5802	1N5804	1N5806	UNITS
Maximum Average Forward Current	I _{F(AV)}	PCB mounted; T _A = 55°C for sine wave for square wave (d = 0.5)		А		
Maximum Average Forward Current	I _{F(AV)}	$T_L = 55^{\circ}C; L = 0$ " for sine wave for square wave		А		
Maximum I ² t for Fusing	l ² t	t = 8.3mS, sine wave	10.0			A ² S
Maximum Forward Voltage Drop	V _F	$I_F = 1.0A, T_j = 25^{\circ}C$	0.875		V	
Maximum Reverse Current	I _R	V_{RWM} , $T_j = 25$ °C		1.0		μΑ
		V_{RWM} , $T_j = 100$ °C		50		μA
Maximum Reverse Recovery Time	trr	$I_F = 1.0A$ to $I_{RRM} = 1.0A$ Recovers to $I_{RR} = 0.1A$	25		nS	
Maximum Junction Capacitance	C _j	$V_R = -5V$, $f = 1MHz$	25		pF	

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	CONDITIONS	1N5802	1N5804	1N5806	UNITS
Maximum Thermal Resistance Junction to Tab	$R_{\scriptscriptstyle{ ext{ heta}jt}}$			20		°C/W



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ELECTRICAL CHARACTERISTICS CURVES

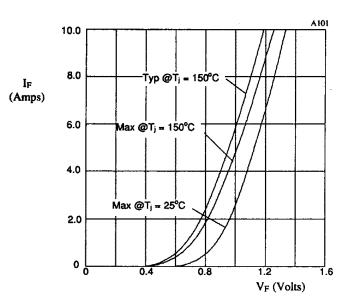


Fig 1. Forward voltage drop as a function of forward current.

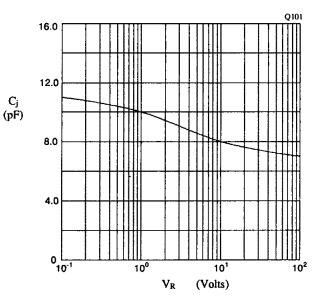


Fig 2. Typical junction capacitance as a function of reverse voltage.